HALOGEN

FREE





## Low Voltage, 0.6 $\Omega$ , Dual SPDT Analog Switch

#### DESCRIPTION

The DG2735A is low voltage, low on-resistance, dual singlepole/double-throw (SPDT) monolithic CMOS analog switches designed for high performance switching of analog signals. Combining low-power, high speed, low on-resistance, and small package size, the DG2735A is ideal for portable and battery power applications.

The DG2735A have an operation range from 1.65 V to 4.3 V single supply. The DG2735A has two separate control pins with for the separated two SPDT switched.

The DG2735A is guaranteed 1.65 V logic compatible, allowing the easy interface with low voltage DSP or MCU control logic and ideal for one cell Li-ion battery direct power.

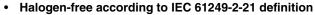
The switch conducts signals within power rails equally well in both directions when on, and blocks up to the power supply level when off. Break-before-make is guaranteed.

The DG2735A is built on Vishav Siliconix's sub micron CMOS low voltage process technology and provides greater than 300 mA latch-up protection, as tested per JESD78.

As a committed partner to the community and the environment, Vishay Siliconix manufactures this product with lead (Pb)-free device terminations. DG2735A is offered in a miniQFN package. The miniQFN package has a nickelpalladium-gold device termination and is represented by the lead (Pb)-free "-E4" suffix. The nickel-palladium-gold device terminations meet all JEDEC standards for reflow and MSL ratings.

#### **FEATURES**

- Low voltage operation (1.65 V to 4.3 V)
- Low on-resistance  $R_{ON}$ : 0.6  $\Omega$  at 2.7 V
- Fast switching: t<sub>ON</sub> = 64 ns at 2.7 V  $t_{OFF} = 42 \text{ ns at } 2.7 \text{ V}$
- Latch-up current > 300 mA (JESD78)





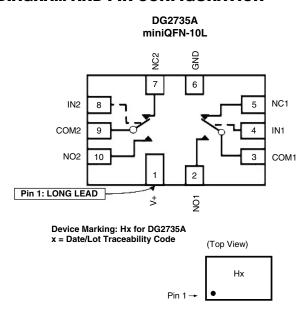
### BENEFITS

- Reduced power consumption
- High accuracy
- Reduce board space
- TTL/1.65 V logic compatible

#### **APPLICATIONS**

- · Cellular phones
- Speaker headset switching
- Audio and video signal routing
- PCMCIA cards
- Battery operated systems
- Portable media player handheld test instruments

#### **FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION**



Note: Pin 1 has long lead



TRUTH TABLE						
Logic	NC	NO				
0	ON	OFF				
1	OFF	ON				

ORDERING INFORMATION							
Temp. Range Package Part Number							
- 40 °C to 85°C	miniQFN10	DG2735ADN-T1-GE4					

<b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>A</sub> = 25 °C, unless otherwise noted)						
Parameter		Symbol	Limit	Unit		
Reference to GND	V+		- 0.3 to 5.0	V		
neleterice to GND	IN, COM, NC, NO <sup>a</sup>		- 0.3 to (V+ + 0.3)	¬		
Current (Any terminal except NO, NC or COM)			30			
Continuous Current (NO, NC, or COM)		± 250		mA		
Peak Current (Pulsed at 1 ms, 10 % duty cycle)			± 500	1		
Storage Temperature (D Suffix)			- 65 to 150	°C		
Power Dissipation (Packages) <sup>b</sup>	miniQFN10 <sup>c</sup>		208	mW		

### Notes:

- a. Signals on NC, NO, or COM or IN exceeding V+ will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
- b. All leads welded or soldered to PC board.
- c. Derate 4.0 mW/C above 70 °C.

SPECIFICATIONS (V+ = 3 V)							
		Test Conditions Limits Unless Otherwise Specified - 40 °C to 85 °C			°C		
Parameter	Symbol	Unless Otherwise Specified V+ = 3 V, $\pm$ 10 %,V <sub>IN</sub> = 0.4 V or 1.65 V <sup>e</sup>		Min.b	Typ. <sup>c</sup>	Max.b	Unit
Analog Switch		/ IIV			, ,		
Analog Signal Range <sup>d</sup>	V <sub>ANALOG</sub>	r <sub>DS(on)</sub>	Full	0		V+	V
		$V+ = 2.7 \text{ V}, I_{NO/NC} = 100 \text{ mA}, V_{COM} = 0.5 \text{ V}$	Doom		0.5	0.0	Ω
		$V+ = 2.7 \text{ V}, I_{NO/NC} = 100 \text{ mA}, V_{COM} = 1.5 \text{ V}$	Room		0.5	0.6	
		$V+ = 2.7 \text{ V}, I_{NO/NC} = 100 \text{ mA}, V_{COM} = 0.5 \text{ V}$	Full		0.6		
On-Resistance	B	$V+ = 2.7 \text{ V}, I_{NO/NC} = 100 \text{ mA}, V_{COM} = 1.5 \text{ V}$	Full		0.0		
On-nesistance	R <sub>DS(on)</sub>	$V+ = 4.3 \text{ V}, I_{NO/NC} = 100 \text{ mA}, V_{COM} = 0.9 \text{ V}$	Room		0.4	0.5	
		$V+ = 4.3 \text{ V}, I_{NO/NC} = 100 \text{ mA}, V_{COM} = 2.5 \text{ V}$	HOOIII		0.4		
		$V+ = 4.3 \text{ V}, I_{NO/NC} = 100 \text{ mA}, V_{COM} = 0.9 \text{ V}$	- Full		0.4		
		$V+ = 4.3 \text{ V}, I_{NO/NC} = 100 \text{ mA}, V_{COM} = 2.5 \text{ V}$	i uli		0.4		
	ΔR <sub>ON</sub>	$V+ = 2.7 \text{ V}, I_{NO/NC} = 100 \text{ mA},$				0.08	
R <sub>ON</sub> Match <sup>d</sup>		V <sub>COM</sub> = 0.5 V, 1.5 V	Room		0.06		
ON		$V+ = 4.3 \text{ V}, I_{NO/NC} = 100 \text{ mA},$					
	В	$V_{COM} = 0.9 \text{ V}, 2.5 \text{ V}$ V+ = 2.7 V, I <sub>NO/NC</sub> = 100 mA,					
R <sub>ON</sub> resistance flatness <sup>d</sup>	R <sub>ON</sub> flatness	$V_{\text{COM}} = 2.7 \text{ V, } I_{\text{NO/NC}} = 100 \text{ mA,}$ $V_{\text{COM}} = 0.5 \text{ V, } 1.5 \text{ V}$	Room			0.15	
		TOOM STOLEN, TO T	Room	- 10		10	
Switch Off Leakage	I <sub>NO/NC(off)</sub>	$V+ = 4.3 \text{ V}, V_{NO/NC} = 0.3 \text{ V}/4.0 \text{ V},$	Full	- 50		50	
Current	I <sub>COM(off)</sub>	$V_{COM} = 4.0 \text{ V/}0.3 \text{ V}$		- 10		10	_
			Full	- 50		50	nA
Channel-On Leakage	annel-On Leakage		Room	- 20		20	
Current	I <sub>COM(on)</sub>	$V_{+} = 4.3 \text{ V}, V_{NO/NC} = V_{COM} = 4.0 \text{ V}/0.3 \text{ V}$ Full		- 100		100	
Digital Control							
Input High Voltage	V <sub>INH</sub>		Full	1.65			V
Input Low Voltage	V <sub>INL</sub>		Full			0.4	v
Input Capacitance	C <sub>IN</sub>		Full		6		pF
Input Current	I <sub>INL</sub> or I <sub>INH</sub>	$V_{IN} = 0$ or $V+$	Full	- 1		1	μΑ



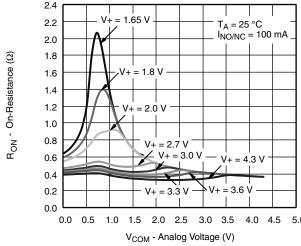


SPECIFICATIONS (V+ = 3 V)								
		Test Conditions Unless Otherwise Specified		Limits - 40 °C to 85 °C				
Parameter	Symbol	$V+ = 3 V$ , $\pm 10 \%$ , $V_{IN} = 0.4 V$ or 1.65 $V^e$	Temp.a	Min.b	Typ. <sup>c</sup>	Max.b	Unit	
Dynamic Characteristics								
Break-Before-Make Time <sup>e</sup>	t <sub>BBM</sub>		Room	1	11			
Turn-On Time <sup>e</sup>	t <sub>ON</sub>	V: 26VV V 15VD 500	Room		44	75	ns	
Tutti-Off Tillie		V+ = 3.6 V, $V_{NO}$ , $V_{NC}$ = 1.5 V, $R_L$ = 50 Ω, $C_1$ = 35 pF	Full			80		
Turn-Off Time <sup>e</sup>	+	ομ – 33 βι	Room		26	55		
Turn-On Time	t <sub>OFF</sub>		Full			60		
Off-Isolation <sup>d</sup>	O <sub>IRR</sub>	P = 50 0 C = 5 pE f = 100 kHz	Room		- 70		dB	
Crosstalk <sup>d</sup>	X <sub>TALK</sub>	$R_L = 50 \Omega$ , $C_L = 5 pF$ , $f = 100 kHz$	HOOIII		- 70			
3dB bandwith <sup>d</sup>		$R_L = 50 \Omega, C_L = 5 pF$	Room		30		MHz	
NO, NC Off Capacitance <sup>d</sup>	C <sub>NO(off)</sub>	V 0V 24V 6 4 MHz	Room		52		pF	
NO, NO On Capacitance	C <sub>NC(off)</sub>				52			
Channal On Canaditanad	C <sub>NO(on)</sub>	$V_{IN} = 0 \text{ V, or V+, f} = 1 \text{ MHz}$			168			
Channel On Capacitance <sup>d</sup>	C <sub>NC(on)</sub>				168			
Power Supply								
Power Supply Range	V+			1.65		4.3	V	
Power Supply Current	l+	V <sub>IN</sub> = 0 or V+	Full			1.0	μΑ	

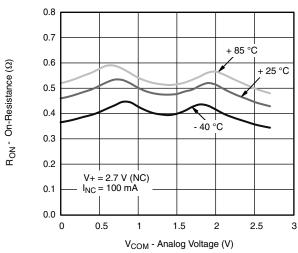
- a. Room = 25 °C, Full = as determined by the operating suffix.
- b. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
- c. Typical values are for design aid only, not guaranteed nor subject to production testing.
- d. Guarantee by design, not subjected to production test.
- e.  $V_{IN}$  = input voltage to perform proper function.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

## TYPICAL CHARACTERISTICS (T<sub>A</sub> = 25 °C, unless otherwise noted)

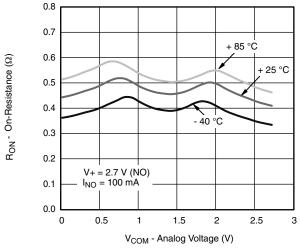




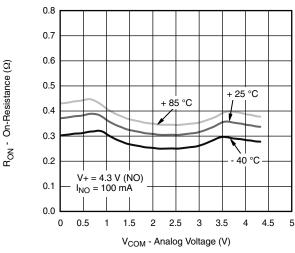


 $\rm R_{ON}$  vs.  $\rm V_{COM}$  and Single Supply Voltage

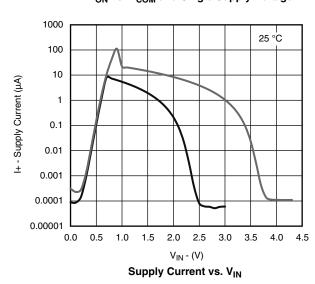
## **TYPICAL CHARACTERISTICS** (T<sub>A</sub> = 25 °C, unless otherwise noted)

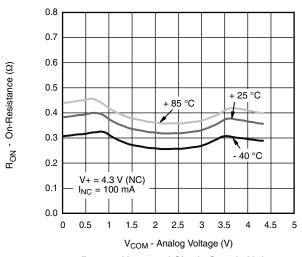


 $R_{ON}$  vs.  $V_{COM}$  and Single Supply Voltage

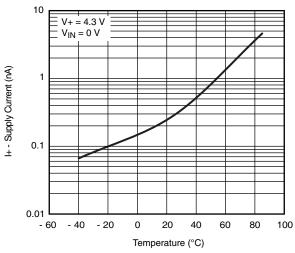


 $R_{ON}$  vs.  $V_{COM}$  and Single Supply Voltage

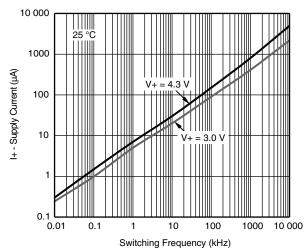




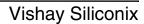
 $\rm R_{ON}$  vs.  $\rm V_{COM}$  and Single Supply Voltage



I+ Supply Current vs. Temperature

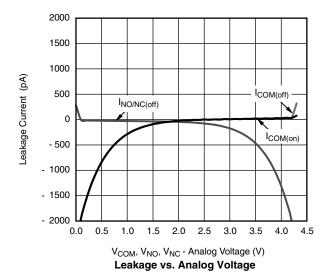


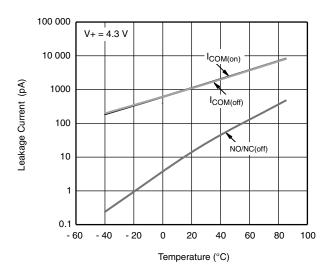
**Supply Current vs. Switching Frequency** 



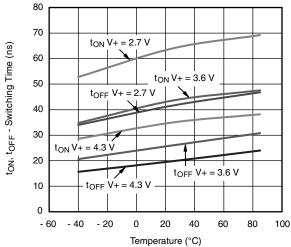


## **TYPICAL CHARACTERISTICS** (T<sub>A</sub> = 25 °C, unless otherwise noted)

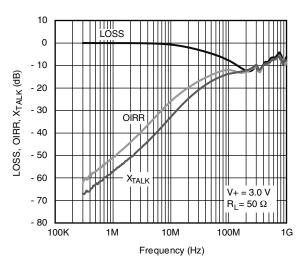




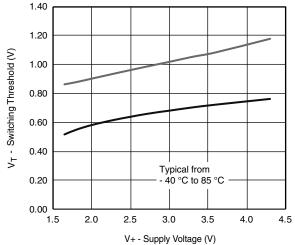
Leakage Current vs. Temperature



Switching Time vs. Temperature

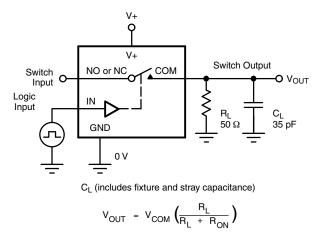


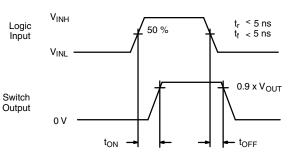
Insertion Loss, Off-Isolation Crosstalk vs. Frequency



Switching Threshold vs. Supply Voltage

## **TEST CIRCUITS**





Logic "1" = Switch On Logic input waveforms inverted for switches that have the opposite logic sense.

Figure 1. Switching Time

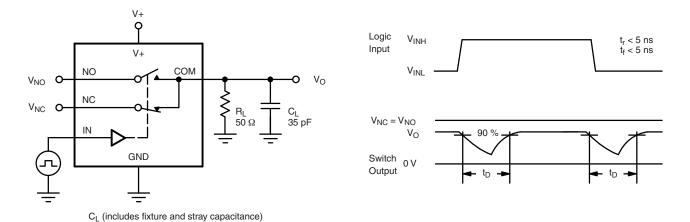
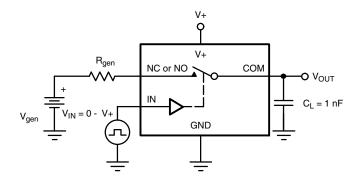
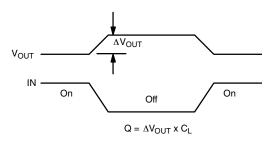


Figure 2. Break-Before-Make Interval



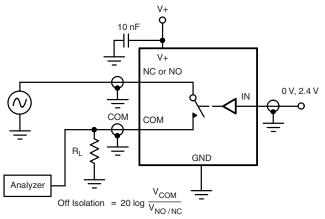
### **TEST CIRCUITS**





IN depends on switch configuration: input polarity determined by sense of switch.

Figure 3. Charge Injection





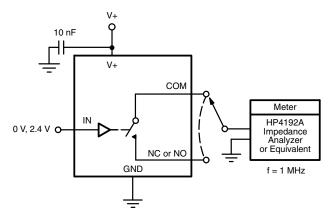
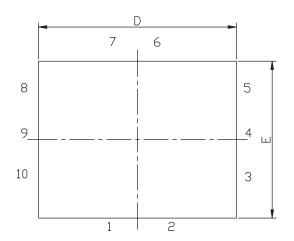


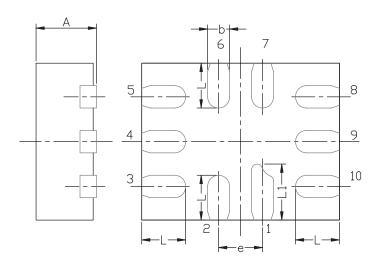
Figure 5. Channel Off/On Capacitance

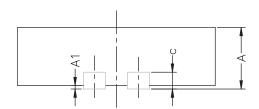
Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?67590.



## **MINI QFN-10L CASE OUTLINE**







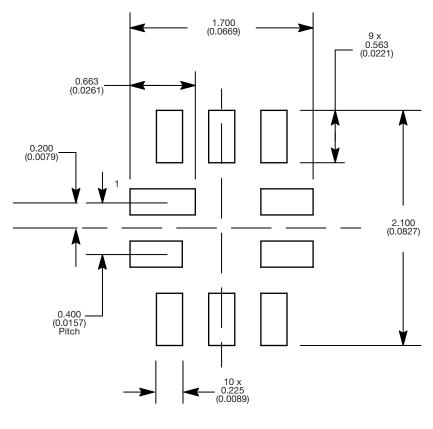
DIM	M	ILLIMETER	IS .		INCHES	INCHES	
	MIN.	NAM.	MAX.	MIN.	NAM.	MAX.	
Α	0.50	0.55	0.60	0.0197	0.0217	0.0236	
A1	0.00	-	0.05	0.000	-	0.002	
b	0.15	0.20	0.25	0.006 0.008 0.01			
С	0.15 REF			0.006 REF			
D	1.75	1.80	1.85	0.069 0.071 0.07		0.073	
E	1.35	1.40	1.45	0.053	0.055	0.057	
е		0.40 BSC		0.016 BSC			
L	0.35	0.40	0.45	0.014	0.016	0.018	
L1	0.45	0.50	0.55	0.0177	0.0197	0.0217	

ECN T-07039-Rev. A, 12-Feb-07

DWG: 5957



## **RECOMMENDED MINIMUM PADS FOR MINI QFN 10L**



Mounting Footprint Dimensions in mm (inch)



## **Legal Disclaimer Notice**

Vishay

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Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

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Revision: 02-Oct-12 Document Number: 91000